

Vishay Semiconductors

Hyperfast Rectifier, 15 A FRED Pt[®]





2L TO-220AC Base cathode 2 O





Cathode Anode

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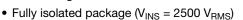
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Cathode Anode

PRODUCT SUMMARY					
Package	2L TO-220AC, 2L TO-220FP				
I _{F(AV)}	15 A				
V _R	600 V				
V _F at I _F	2.45 V				
t _{rr} (typ.)	21 ns				
T _J max.	175 °C				
Diode variation	Single die				

FEATURES

- Hyperfast soft recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current



- True 2 pin package
- Compliant to RoHS Directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21 definition
- Designed and qualified according to JEDEC-JESD47

DESCRIPTION/APPLICATIONS

Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage	V _{RRM}		600	V		
Average restified forward surrent in DC	- I _{F(AV)}	T _C = 149 °C	15	А		
Average rectified forward current in DC		T _C = 94 °C	15			
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	160			
Operating junction and storage temperatures	T _J , T _{Stg}		- 65 to 175	°C		

ELECTRICAL SPECIFICATIONS (T _J = 25 $^{\circ}$ C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-		
Forward voltage	V _F	I _F = 15 A	-	1.8	2.45	2.45 V	
		I _F = 15 A, T _J = 150 °C	-	1.25	1.6		
Deveras leakage everent		$V_{R} = V_{R}$ rated	-	0.01	15		
Reverse leakage current		$T_J = 150 \ ^{\circ}C, V_R = V_R \text{ rated}$	-	20	200	μA	
Junction capacitance	CT	V _R = 600 V	-	12	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8	-	nH	

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e3 RoHS compliant HALOGEN FREE

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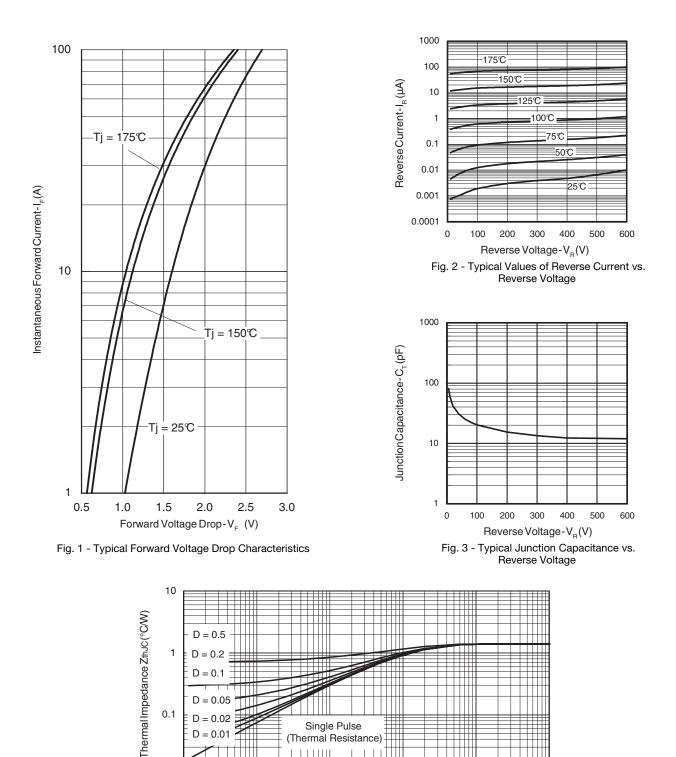
DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS
		$I_F = 1 \text{ A}, dI_F/dt = 10$	$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, V_R = 30 \text{ V}$		21	26	
Povereo recovery time	+	$I_F = 15 \text{ A}, \text{ d}I_F/\text{d}t = 1000 \text{ cm}^{-1}$	$I_F = 15 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		25	36	
Reverse recovery time	t _{rr}	T _J = 25 °C		-	29	-	ns
		T _J = 125 °C	I _F = 15 A dI _F /dt = 200 A/μs V _B = 390 V	-	65	-	
Deal and a second		T _J = 25 °C		-	3.9	-	А
Peak recovery current	I _{RRM}	T _J = 125 °C			-	7.0	-
	0	T _J = 25 °C		-	60	-	nC
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	240	-	nc
Reverse recovery time	t _{rr}	$T_J = 125 \text{ °C}$ $d_{I_F}/dt = 800 \text{ A/}\mu\text{s}$	I _F = 15 A	-	42	-	ns
Peak recovery current	I _{RRM}		dl _F /dt = 800 A/µs	-	21	-	А
Reverse recovery charge	Q _{rr}		-	480	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		- 65	-	175	°C	
Thermal resistance,	D		-	1.2	1.4		
junction to case FULL-PAK	R _{thJC}		-	3.7	4.3		
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	70	°C/W	
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-		
			-	2	-	g	
Weight			-	0.07	-	oz.	
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)	
		Case style 2L TO-220AC	ETH1506		•		
Marking device		Case style 2L TO-220 FULL-PAK		ETH1	506FP		

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1E-03

1E-04

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Revision: 11-Mar-11

t1,RectangularPulseDuration(Seconds) Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

1E-02

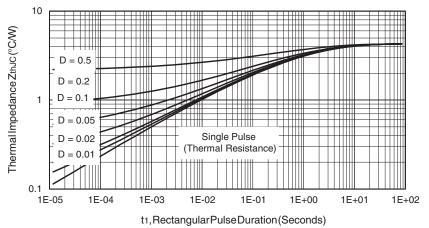
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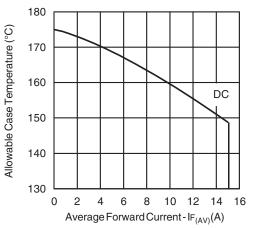
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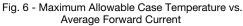
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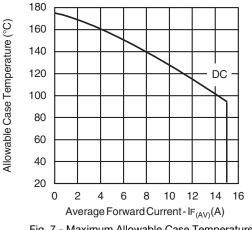


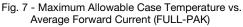


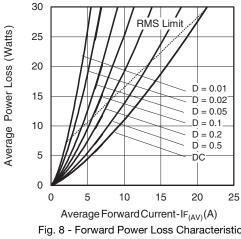


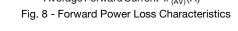












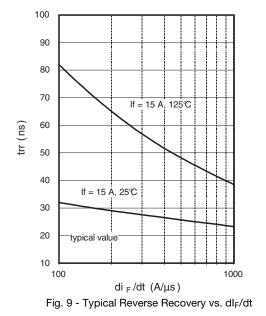
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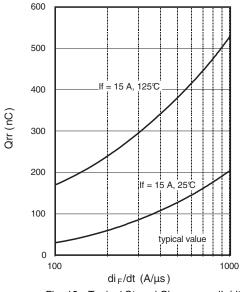
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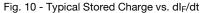
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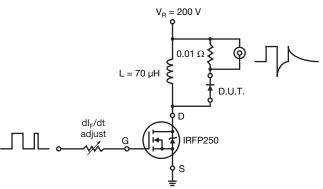
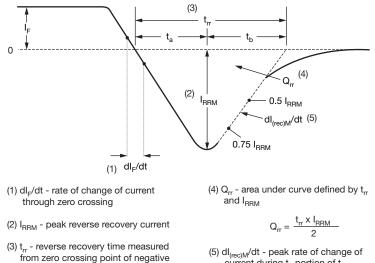


Fig. 11 - Reverse Recovery Parameter Test Circuit



current during t_b portion of t_{rr}

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Fig. 12 - Reverse Recovery Waveform and Definitions

going I_F to point where a line passing through 0.75 $\mathrm{I}_{\mathrm{RRM}}$ and 0.50 $\mathrm{I}_{\mathrm{RRM}}$ extrapolated to zero current.

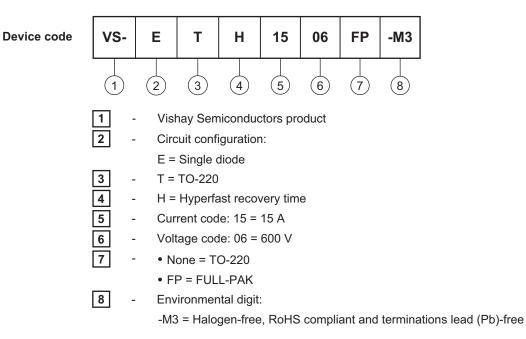
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ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)						
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-ETH1506-M3	50	1000	Antistatic plastic tube			
VS-ETH1506FP-M3	50	1000	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS					
Dimonoione	2L TO-220AC	www.vishay.com/doc?95259			
Dimensions	2L TO-220 FULL-PAK	www.vishay.com/doc?95260			
Port marking information	2L TO-220AC	www.vishay.com/doc?95391			
Part marking information	2L TO-220 FULL-PAK	www.vishay.com/doc?95392			

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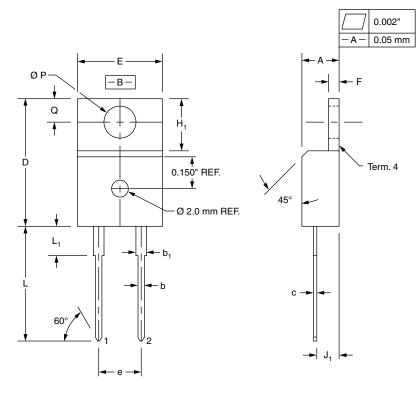
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Vishay High Power Products

True 2 Pin TO-220

DIMENSIONS in millimeters and inches

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SYMBOL	MILLIN	IETERS	INCH	ES
STMDUL	MIN.	MAX.	MIN.	MAX.
A	4.32	4.57	0.170	0.180
b	0.71	0.91	0.028	0.036
b ₁	1.15	1.39	0.045	0.055
С	0.36	0.53	0.014	0.021
D	14.99	15.49	0.590	0.610
E	10.04	10.41	0.395	0.410
e	5.08	BSC	0.200 E	SC
F	1.22	1.37	0.048	0.054
H ₁	5.97	6.47	0.235	0.255
J ₁	2.54	2.79	0.100	0.110
L	13.47	13.97	0.530	0.550
L ₁ ⁽¹⁾	3.31	3.81	0.130	0.150
ØP	3.79	3.88	0.149	0.153
Q	2.60	2.84	0.102	0.112

Notes

 $^{\left(1\right)}$ Lead dimension and finish uncontrolled in L_{1}

• These dimensions are within allowable dimensions of JEDEC TO-220AB rev. J outline dated 3-24-87

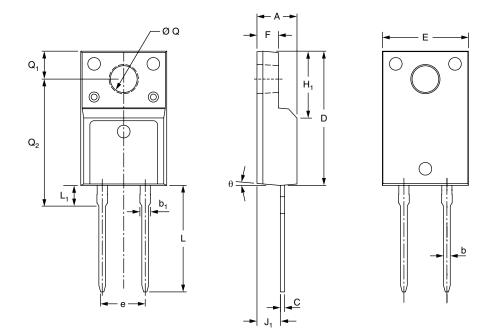
Controling dimension: Inch

Vishay High Power Products

True 2 Pin TO-220 FULL-PAK

DIMENSIONS in millimeters and inches

VISHAY



SYMBOL	MILLIN	METERS	INCH	IES
STMBOL	MIN.	MAX.	MIN.	MAX.
A	4.53	4.93	0.178	0.194
b	0.71	0.91	0.028	0.036
b ₁	1.15	1.39	0.045	0.055
С	0.36	0.53	0.014	0.021
D	15.67	16.07	0.617	0.633
E	9.96	10.36	0.392	0.408
e	5.08	typical	0.200 ty	ypical
F	2.34	2.74	0.092	0.107
H ₁	6.50	6.90	0.256	0.272
J ₁	2.56	2.96	0.101	0.117
L	12.78	13.18	0.503	0.519
L ₁	2.23	2.63	0.088	0.104
ØQ	2.98	3.38	0.117	0.133
Q ₁	3.10	3.50	0.122	0.138
Q2	14.80	15.20	0.583	0.598
θ	0°	5°	0°	5°



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